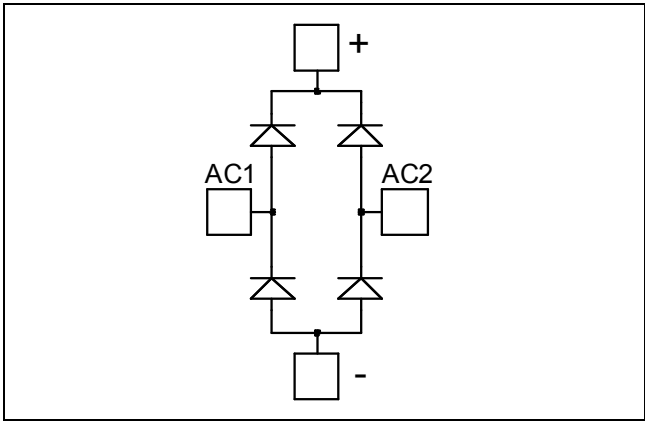


Diode Full Bridge Power Module

$V_{RRM} = 1200V$
 $I_C = 200A @ T_c = 60^\circ C$

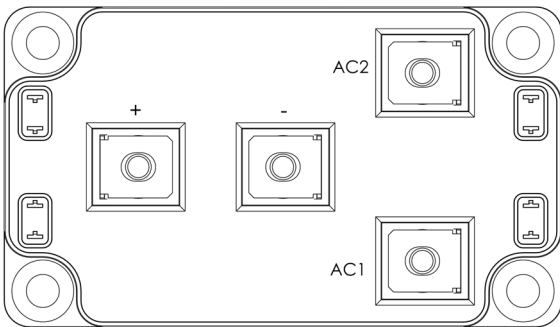


Application

- Uninterruptible Power Supply (UPS)
- Induction heating
- Welding equipment
- High speed rectifiers

Features

- Ultra fast recovery times
- Soft recovery characteristics
- High blocking voltage
- High current
- Low leakage current
- Very low stray inductance
 - Symmetrical design
 - M5 power connectors
- High level of integration



Benefits

- Outstanding performance at high frequency operation
- Low losses
- Low noise switching
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- RoHS Compliant

All ratings @ $T_j = 25^\circ C$ unless otherwise specified

Absolute maximum ratings

Symbol	Parameter	Max ratings	Unit
V_R	Maximum DC reverse Voltage	1200	V
V_{RRM}	Maximum Peak Repetitive Reverse Voltage		
$I_{F(AV)}$	Maximum Average Forward Current	Duty cycle = 50% $T_C = 25^\circ C$	235
		$T_C = 60^\circ C$	200
$I_{F(RMS)}$	RMS Forward Current	Duty cycle = 50% $T_C = 45^\circ C$	235
I_{FSM}	Non-Repetitive Forward Surge Current	8.3ms $T_C = 45^\circ C$	1500

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

Electrical Characteristics

<i>Symbol</i>	<i>Characteristic</i>	<i>Test Conditions</i>		<i>Min</i>	<i>Typ</i>	<i>Max</i>	<i>Unit</i>
V _F	Diode Forward Voltage	I _F = 200A			2.4	3.0	V
		I _F = 300A			2.7		
		I _F = 200A	T _j = 125°C		1.8		
I _{RM}	Maximum Reverse Leakage Current	V _R = 1200V	T _j = 25°C			150	μA
			T _j = 125°C			600	
C _T	Junction Capacitance	V _R = 1200V			220		pF

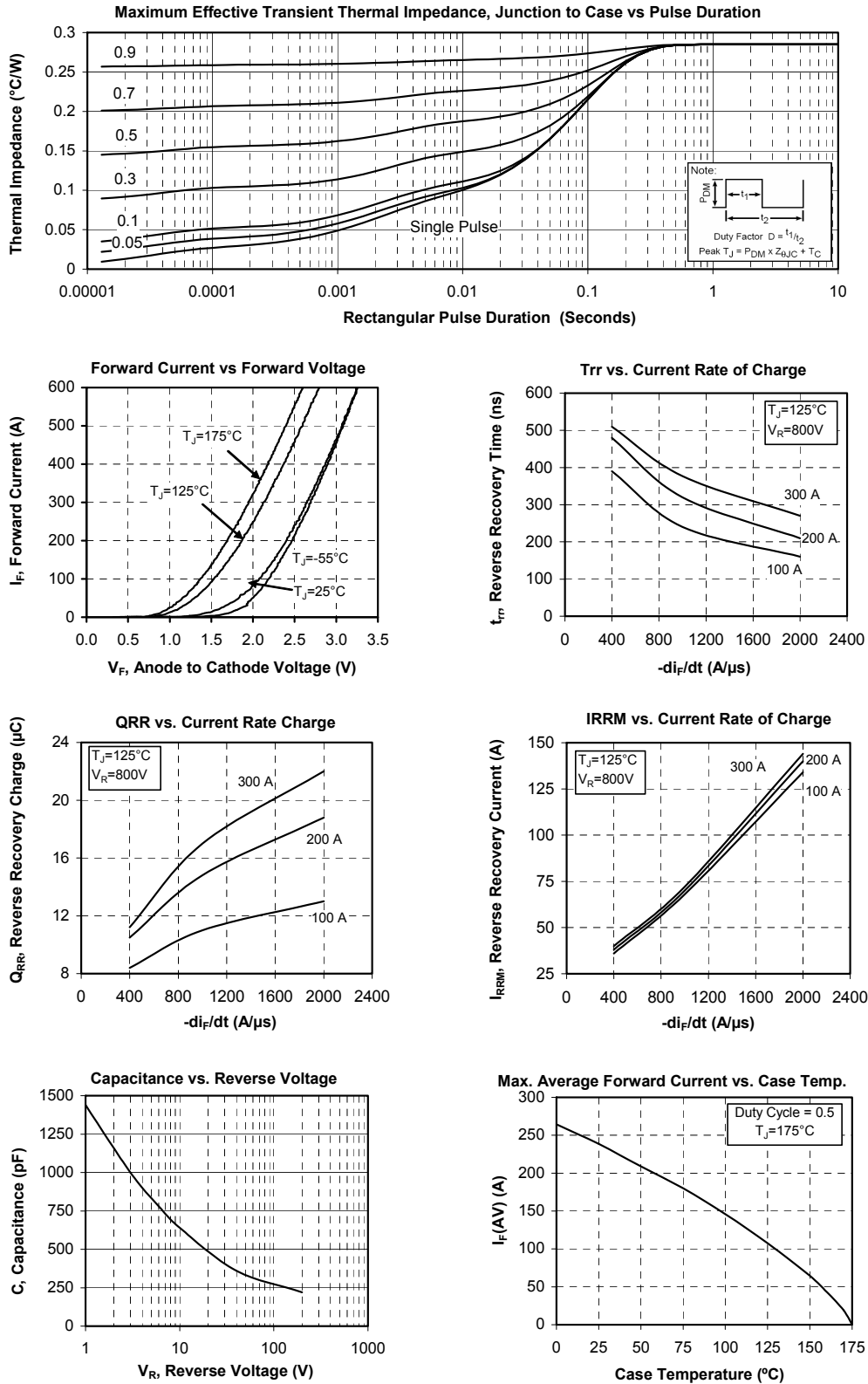
Dynamic Characteristics

<i>Symbol</i>	<i>Characteristic</i>	<i>Test Conditions</i>		<i>Min</i>	<i>Typ</i>	<i>Max</i>	<i>Unit</i>	
t _{rr}	Reverse Recovery Time	I _F =1A, V _R =30V	T _j = 25°C		45		ns	
t _{rr}	Reverse Recovery Time	I _F = 200A V _R = 800V di/dt = 400A/μs	T _j = 25°C		385		ns	
			T _j = 125°C		480			
Q _{rr}	Reverse Recovery Charge		T _j = 25°C		2.1		μC	
			T _j = 125°C		10.5			
I _R RM	Reverse Recovery Current		T _j = 25°C		12		A	
			T _j = 125°C		38			
t _{rr}	Reverse Recovery Time		I _F = 200A V _R = 800V di/dt=2000A/μs	T _j = 125°C		210		ns
Q _{rr}	Reverse Recovery Charge					19		μC
I _R RM	Reverse Recovery Current				140		A	

Thermal and package characteristics

<i>Symbol</i>	<i>Characteristic</i>			<i>Min</i>	<i>Typ</i>	<i>Max</i>	<i>Unit</i>
R _{thJC}	Junction to Case Thermal Resistance					0.285	°C/W
V _{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T _J	Operating junction temperature range			-40		175	°C
T _{STG}	Storage Temperature Range			-40		125	
T _C	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M6	3		5	N.m
		For terminals	M5	2		3.5	
Wt	Package Weight					300	g

Typical Performance Curve



DISCLAIMER

The information contained in the document (unless it is publicly available on the Web without access restrictions) is PROPRIETARY AND CONFIDENTIAL information of Microsemi and cannot be copied, published, uploaded, posted, transmitted, distributed or disclosed or used without the express duly signed written consent of Microsemi. If the recipient of this document has entered into a disclosure agreement with Microsemi, then the terms of such Agreement will also apply. This document and the information contained herein may not be modified, by any person other than authorized personnel of Microsemi. No license under any patent, copyright, trade secret or other intellectual property right is granted to or conferred upon you by disclosure or delivery of the information, either expressly, by implication, inducement, estoppels or otherwise. Any license under such intellectual property rights must be approved by Microsemi in writing signed by an officer of Microsemi.

Microsemi reserves the right to change the configuration, functionality and performance of its products at anytime without any notice. This product has been subject to limited testing and should not be used in conjunction with life-support or other mission-critical equipment or applications. Microsemi assumes no liability whatsoever, and Microsemi disclaims any express or implied warranty, relating to sale and/or use of Microsemi products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright or other intellectual property right. Any performance specifications believed to be reliable but are not verified and customer or user must conduct and complete all performance and other testing of this product as well as any user or customers final application. User or customer shall not rely on any data and performance specifications or parameters provided by Microsemi. It is the customer's and user's responsibility to independently determine suitability of any Microsemi product and to test and verify the same. The information contained herein is provided "AS IS, WHERE IS" and with all faults, and the entire risk associated with such information is entirely with the User. Microsemi specifically disclaims any liability of any kind including for consequential, incidental and punitive damages as well as lost profit. The product is subject to other terms and conditions which can be located on the web at <http://www.microsemi.com/legal/tnc.asp>

Life Support Application

Seller's Products are not designed, intended, or authorized for use as components in systems intended for space, aviation, surgical implant into the body, in other applications intended to support or sustain life, or for any other application in which the failure of the Seller's Product could create a situation where personal injury, death or property damage or loss may occur (collectively "Life Support Applications").

Buyer agrees not to use Products in any Life Support Applications and to the extent it does it shall conduct extensive testing of the Product in such applications and further agrees to indemnify and hold Seller, and its officers, employees, subsidiaries, affiliates, agents, sales representatives and distributors harmless against all claims, costs, damages and expenses, and attorneys' fees and costs arising, directly or indirectly, out of any claims of personal injury, death, damage or otherwise associated with the use of the goods in Life Support Applications, even if such claim includes allegations that Seller was negligent regarding the design or manufacture of the goods.

Buyer must notify Seller in writing before using Seller's Products in Life Support Applications. Seller will study with Buyer alternative solutions to meet Buyer application specification based on Sellers sales conditions applicable for the new proposed specific part.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for [Discrete Semiconductor Modules](#) category:

Click to view products by [Microchip](#) manufacturer:

Other Similar products are found below :

[M252511FV](#) [M254043](#) [DD260N12K-A](#) [DD380N16A](#) [DDB6U144N16R](#) [DDB6U145N16L](#) [DR7306](#) [APT20M11JFLL](#) [APT2X101DL40J](#)
[APT2X21DC60J](#) [APT2X30D40J](#) [APT2X30D60J](#) [APT2X31DQ120J](#) [APT39M60J](#) [APT47M60J](#) [APT50DF170HJ](#) [APT50M50JLL](#)
[APT50M75JLLU3](#) [APT50N60JCCU2](#) [APT58M80J](#) [APT80F60J](#) [DZ540N26K](#) [B522F-2-YEC](#) [MSTC90-16](#) [MT16HTF12864AZ-800G1](#)
[MT18HTF12872PZ-667G1](#) [MT18HTF25672FDZ-667H1D6](#) [MT18HTF25672PZ-80EH1](#) [MT18RTF25672FDZ-667H1D6](#)
[MT36HTF51272FZ-667H1D4](#) [MT36HTF51272FZ-667H1D6](#) [MT8HTF12864HTZ-667H1](#) [MT9HTF6472PZ-667G1](#) [MT9HVF12872PZ-](#)
[80EH1](#) [MT9HVF6472PZ-667G1](#) [ND104N16K](#) [25.163.0653.1](#) [25.163.2453.0](#) [25.163.4253.0](#) [25.190.2053.0](#) [25.194.3453.0](#) [25.320.4853.1](#)
[25.320.5253.1](#) [25.325.3653.1](#) [25.326.3253.1](#) [25.326.3553.1](#) [25.330.1653.1](#) [25.330.4753.1](#) [25.330.5253.1](#) [25.334.3253.1](#)